

**IN THE CLAIMS**

Claims 1-13 (Canceled).

14 (Previously Presented). A process comprising:  
forming a recess having a bottom and a wall;  
forming an electrically resistive film in the recess to form a heater; and  
treating the film to have different electrical conductivity at the bottom and the  
wall; and  
forming a phase change material over said wall.

15 (Currently Amended). The process according to claim 14, wherein treating  
includes implanting the film at a first angle and implanting the ~~polysilicon~~ film at a second angle  
different from the first angle.

16 (Previously Presented). The process according to claim 14, wherein treating further  
comprises doping the film to form discrete isolated regions.

17 (Previously Presented). The process according to claim 14, before treating, further  
comprising:  
forming a temporary material in the recess; and  
patterning the temporary material to expose the film.

18 (Previously Presented). The process according to claim 14, before treating, further  
comprising:  
forming a temporary material in the recess;  
patterning a mask over the temporary material; and  
removing a portion of the temporary material to expose the film.

Claims 19-45 (Canceled).